Thyristor Semiconductor Device - Page 1 of 1

AeroBase Group

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Inclosure Material:

Metal

Overall Length:

2.500 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Overall Width Across Flats:

1.047 inches

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

150.0 breakover voltage, dc

Current Rating Per Characteristic:

70.00 amperes source cutoff current

Power Rating Per Characteristic:

0.5 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 uninsulated wire lead w/terminal lug and 1 threaded stud

Specification Data:

80131-release3317 professional/industrial association specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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